

Title (en)

SYSTEM FOR PRODUCING SILICON WITH IMPROVED RESOURCE UTILIZATION

Title (de)

ANLAGE ZUR HERSTELLUNG VON SILIZIUM MIT VERBESSERTER RESSOURCENNUTZUNG

Title (fr)

INSTALLATION DE PRODUCTION DE SILICIUM PERMETTANT UNE AMÉLIORATION DE L'EXPLOITATION DES RESSOURCES

Publication

**EP 2352582 A1 20110810 (DE)**

Application

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Priority

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- US 11882108 P 20081201

Abstract (en)

[origin: CA2745480A1] The present invention relates to a system for producing silicon, preferably high-purity silicon, particularly solar silicon, and to a method for producing silicon, preferably high-purity silicon, in particular solar silicon, in each case with particularly effective resource utilization and reduced emission of pollutants.

IPC 8 full level

**B01J 19/24** (2006.01); **C01B 33/025** (2006.01)

CPC (source: EP KR US)

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Citation (search report)

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DOCDB simple family (publication)

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JP 2011538937 A 20091119; KR 20117012474 A 20091119; SG 2011039393 A 20091119; TW 98140346 A 20091126;  
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